

	Type	L #	Hits	Search Text	DBs
1	BRS	L1	282385	(heat\$3) near25 (substrate or wafer)	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
2	BRS	L2	202016	(heat\$3) near5 (substrate or wafer)	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
3	BRS	L3	2777	((heat\$3) near5 (substrate or wafer)) near15 (density)	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
4	BRS	L4	332	((heat\$3) near5 (substrate or wafer)) near15 (density) near15 (metal or crystal)	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B

	Time Stamp	Comments	Error Definition	Errors
1	2005/02/02 05:34			
2	2005/02/02 05:34			
3	2005/02/02 05:34			
4	2005/02/02 06:07			

	Type	L #	Hits	Search Text	DBs
5	BRS	L5	9	((heat\$3) near5 (substrate near silicon)) near15 (density) near15 (metal or crystal)	US-PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TDB
6	BRS	L6	68	((heat\$3) near5 (substrate near silicon)) near15 (density)	US-PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TDB
7	BRS	L7	28	((heat\$3) near5 (substrate near silicon)) near15 (oxide) near15 (polysilicon)	US-PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TDB
8	BRS	L8	4235	((substrate near silicon)) near15 (oxide) near15 (polysilicon)	US-PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TDB

	Time Stamp	Comments	Error Definition	Errors
5	2005/02/02 05:47			
6	2005/02/02 05:54			
7	2005/02/02 05:57			
8	2005/02/02 05:57			

	Type	L #	Hits	Search Text	DBs
9	BRS	L9	1087	((substrate near silicon)) near15 (silicon near oxide) near15 (polysilicon)	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
10	BRS	L10	118	((substrate near silicon)) near15 (silicon near oxide) near15 (polysilicon)) near25 (remov\$3)	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
11	BRS	L11	10	"6587036".pn. or "6118686".pn. or "6090666".pn. or "6060743".pn. or "5731598".pn.	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
12	BRS	L12	147	((heat\$3) near5 (substrate or wafer)) near15 (density) near15 (metal or nanocrystal)	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B

	Time Stamp	Comments	Error Definition	Errors
9	2005/02/02 05:57			
10	2005/02/02 06:03			
11	2005/02/02 06:07			
12	2005/02/02 06:09			

	Type	L #	Hits	Search Text	DBs
13	BRS	L13	147	((heat\$3) near5 (substrate or wafer)) near15 (density) near15 (metal or nano-crystal)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
14	BRS	L14	0	((heat\$3) near5 (substrate or wafer)) near15 (density) near15 (nano-crystal)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
15	BRS	L15	0	((heat\$3) near5 (substrate or wafer)) near15 (density) near15 (nanocrystal)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
16	BRS	L16	147	((heat\$3) near5 (substrate or wafer)) near15 (density) near15 (metal)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB

	Time Stamp	Comments	Error Definition	Errors
13	2005/02/02 06:09			
14	2005/02/02 06:09			
15	2005/02/02 06:10			
16	2005/02/02 06:10			

	Type	L #	Hits	Search Text	DBs
1	BRS	L1	11693	(remov\$3) near25 (silicon near substrate)	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
2	BRS	L2	5	(remov\$3) near15 (mono- crystal\$1) near25 (silicon near substrate)	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
3	BRS	L3	5	(remov\$3) near15 (mono near crystal\$1) near25 (silicon near substrate)	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
4	BRS	L4	600	(remov\$3) near15 (crystal\$1) near25 (silicon near substrate)	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B

	Type	L #	Hits	Search Text	DBs
5	BRS	L5	812	(remov\$3) near15 (metal) near25 (silicon near substrate)	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
6	BRS	L6	496	(remov\$3) near5 (metal) near25 (silicon near substrate)	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
7	BRS	L7	1504	(pattern\$3) near15 ((silicon near oxide) near15 (polysilicon))	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
8	BRS	L8	95	(pattern\$3) near15 ((silicon near oxide) near15 (polysilicon)) near25 (metal or crista\$1)	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B

	Type	L #	Hits	Search Text	DBs
9	BRS	L9	154	(etch\$3) near15 ((silicon near oxide) near15 (polysilicon)) near25 (metal or crysta\$1)	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
10	BRS	L10	1504	(pattern\$3) near15 ((silicon near oxide) near15 (polysilicon))	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
11	BRS	L11	18	10 and (quantum)	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
12	BRS	L12	430	10 and (crystal\$1)	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B

	Type	L #	Hits	Search Text	DBs
13	BRS	L13	1044	(pattern\$3) near15 ((silicon near oxide) near5 (polysilicon))	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
14	BRS	L14	0	(pattern\$3) near15 ((silicon near oxide) near5 (polysilicon)) near50 (quantum)	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
15	BRS	L15	0	(pattern\$3) near15 ((silicon near oxide) near5 (polysilicon)) near50 (monocrystal)	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
16	BRS	L16	0	(pattern\$3) near15 ((silicon near oxide) near5 (polysilicon)) near50 (mono-crystal)	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B

	Type	L #	Hits	Search Text	DBs
17	BRS	L17	16	(pattern\$3) near15 ((silicon near oxide) near5 (polysilicon)) near50 (crystal)	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
18	BRS	L18	45	(pattern\$3) near15 ((silicon near oxide) near5 (polysilicon)) near50 (metal)	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
19	BRS	L19	173	(quantum or crystal) near15 ((silicon near oxide) near5 (polysilicon))	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
20	BRS	L20	1925	(quantum or crystal) and ((silicon near oxide) near5 (polysilicon))	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B

	Type	L #	Hits	Search Text	DBs
21	BRS	L21	539	(quantum or crystal) near15 ((oxide) near5 (polysilicon))	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
22	BRS	L22	18	((quantum or crystal) and (pattern\$3)) near5 ((silicon near oxide) near5 (polysilicon))	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
23	BRS	L23	45	((quantum or crystal) and (pattern\$3)) near5 ((oxide) near5 (polysilicon))	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
24	BRS	L24	7	((quantum or crystal) and (pattern\$3)) near5 ((oxide) near5 (poly\$5))	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B

	Type	L #	Hits	Search Text	DBs
25	BRS	L25	21055	((quantum or crystal)) and ((oxide) near5 (poly\$5))	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
26	BRS	L26	1156	((quantum or crystal)) near15 ((oxide) near5 (poly\$5))	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
27	BRS	L27	10	((quantum near dot)) near15 ((oxide) near5 (poly\$5))	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
28	BRS	L28	2	"6767771".pn.	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B